TOPLED®

TOPLED, SMT LED with integrated reflector. With our great experience in SMT LED we are able to offer a high quality product for all kind of applications.









Applications

- Cluster, Button Backlighting
- Electronic Equipment

- Interior Illumination (e.g. Ambient Map)
- White Goods

Features:

- Package: white PLCC-2 package, colorless clear resin
- Chip technology: InGaAIP
- Typ. Radiation: 120° (Lambertian emitter)
- − Color: $λ_{dom}$ = 630 nm (• super red)
- Corrosion Robustness Class: 3B
- Qualifications: AEC-Q102 Qualified
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM)



Ordering Information			
Туре	Luminous Intensity 1) I _F = 2 mA I _v	Ordering Code	
LS T67K-J1L2-1	4.5 18.0 mcd	Q65110A2013	



Maximum Ratings			
Parameter	Symbol		Values
Operating Temperature	T _{op}	min. max.	-40 °C 100 °C
Storage Temperature	T_{stg}	min. max.	-40 °C 100 °C
Junction Temperature	T _j	max.	125 °C
Forward current T _S = 25 °C	I _F	max.	20 mA
Forward current pulsed $t \le 10 \text{ µs}$; D = 0.005 ; T _s = 25 °C	I _{F pulse}	max.	100 mA
Reverse voltage ²⁾ T _S = 25 °C	V_R	max.	12 V
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM)	V_{ESD}		2 kV



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 I_F = 2 mA; T_S = 25 °C

Parameter	Symbol		Values
Peak Wavelength	$\lambda_{\sf peak}$	typ.	645 nm
Dominant Wavelength ³⁾ I _F = 2 mA	λ_{dom}	min. typ. max.	624 nm 630 nm 636 nm
Spectral Bandwidth at 50% I _{rel,max}	Δλ	typ.	16 nm
Viewing angle at 50% $\rm I_{_{ m V}}$	2φ	typ.	120 °
Forward Voltage ⁴⁾ I _F = 2 mA	V_{F}	min. typ. max.	1.70 V 1.80 V 2.20 V
Reverse current ²⁾ V _R = 12 V	I _R	typ. max.	0.01 μA 10 μA
Temperature Coefficient of Peak Wavelength -10°C ≤ T ≤ 100°C	TC_{\lambdapeak}	typ.	0.14 nm / K
Real thermal resistance junction/ambient 5)6)	$R_{ ext{thJA real}}$	max.	420 K / W
Real thermal resistance junction/solderpoint 5)	$R_{ ext{thJS real}}$	max.	260 K / W



Brightness Groups

Group	Luminous Intensity ¹⁾ $I_F = 2 \text{ mA}$ min. I_V	Luminous Intensity. 1) I _F = 2 mA max. I _v	Luminous Flux 7) $I_F = 2 \text{ mA}$ $typ.$ Φ_{V}
J1	4.5 mcd	5.6 mcd	15.1 mlm
J2	5.6 mcd	7.1 mcd	19.0 mlm
K1	7.1 mcd	9.0 mcd	24.2 mlm
K2	9.0 mcd	11.2 mcd	30.3 mlm
L1	11.2 mcd	14.0 mcd	37.8 mlm
L2	14.0 mcd	18.0 mcd	48.0 mlm

Group Name on Label

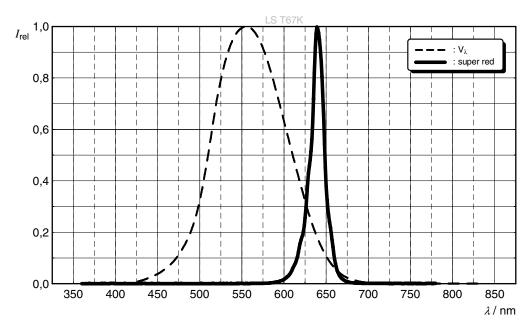
Examp	le:	J1	-1
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Brightness	Wavelength
J1	1



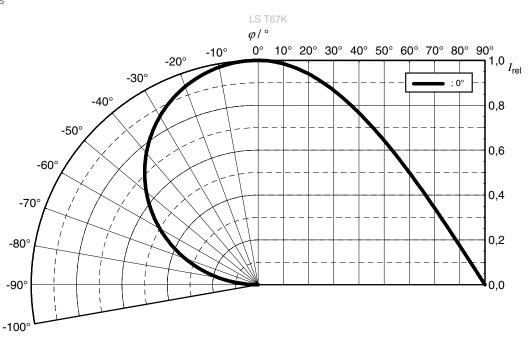
Relative Spectral Emission 7)

$$I_{rel}$$
 = f (λ); I_F = 2 mA; T_S = 25 °C



Radiation Characteristics 7)

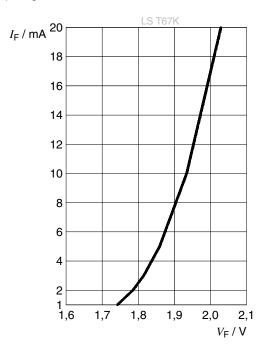
$$I_{rel} = f(\phi); T_S = 25 °C$$





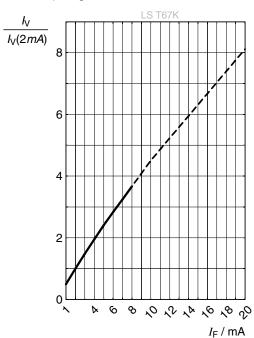
Forward current 7)

$$I_F = f(V_F); T_S = 25 \, ^{\circ}C$$



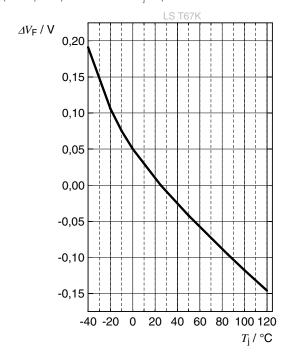
Relative Luminous Intensity 7), 8)

$$I_{V}/I_{V}(2 \text{ mA}) = f(I_{F}); T_{S} = 25 \text{ }^{\circ}\text{C}$$



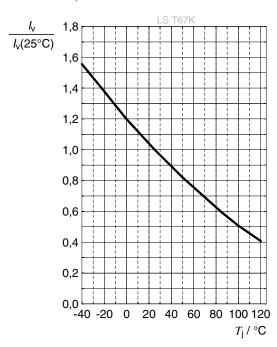
Forward Voltage 7)

$$\Delta V_{_F} = V_{_F} - V_{_F} (25 \ ^{\circ}C) = f(T_{_j}); \ I_{_F} = 2 \ mA$$



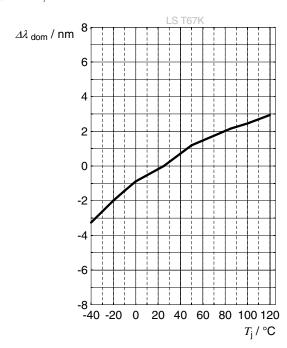
Relative Luminous Intensity 7)

$$I_{v}/I_{v}(25 \text{ °C}) = f(T_{i}); I_{F} = 2 \text{ mA}$$



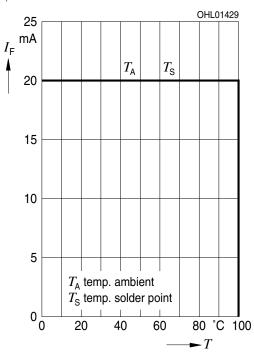
Dominant Wavelength 7)

$$\lambda_{dom} = f(T_j); I_F = 2 \text{ mA}$$



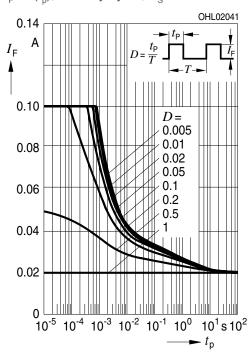
Max. Permissible Forward Current

 $I_{\scriptscriptstyle F} = f(T)$



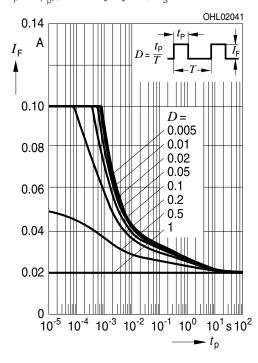
Permissible Pulse Handling Capability

 $I_{_{\rm F}}$ = f($t_{_{
m D}}$); D: Duty cycle; $T_{_{
m S}}$ = 25 °C

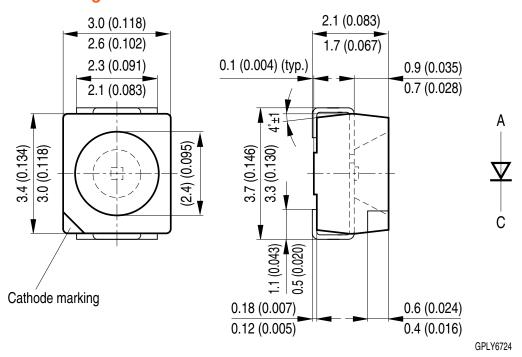


Permissible Pulse Handling Capability

 $I_{_{\rm F}}$ = f(t $_{_{
m D}}$); D: Duty cycle; $T_{_{
m S}}$ = 85 °C



Dimensional Drawing 9)



Further Information:

Approximate Weight: 34.0 mg **Package marking:** Cathode

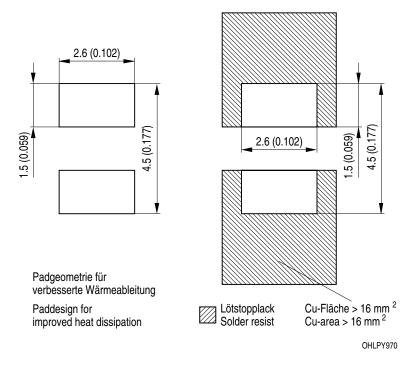
Corrosion test: Class: 3B

Test condition: 40°C / 90 % RH / 15 ppm H₂S / 14 days (stricter than IEC

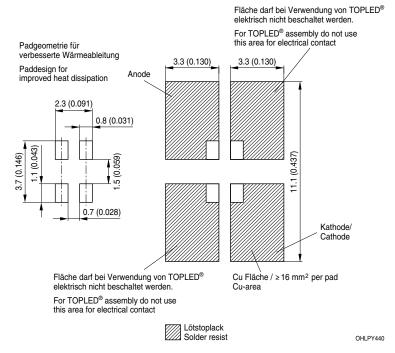
60068-2-43)



Recommended Solder Pad 9)



Recommended Solder Pad 9)

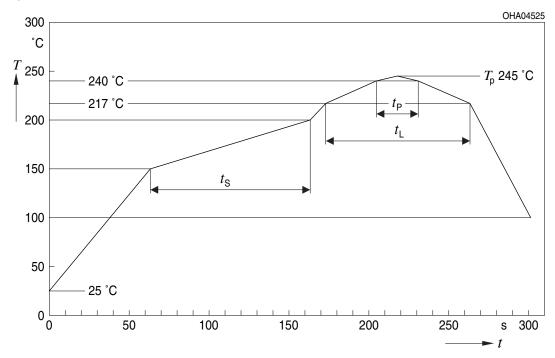


For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Package not suitable for ultra sonic cleaning.



Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



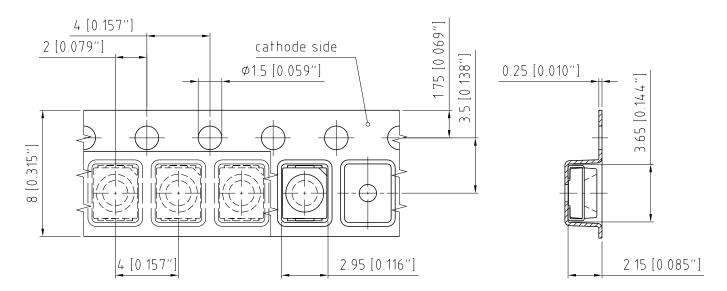
Profile Feature	Symbol	Pb	Pb-Free (SnAgCu) Assembly		
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*)			2	3	K/s
25 °C to 150 °C					
Time t _s	t_s	60	100	120	S
T_{Smin} to T_{Smax}					
Ramp-up rate to peak*)			2	3	K/s
T_{Smax} to T_{P}					
Liquidus temperature	T_L		217		°C
Time above liquidus temperature	$t_{\scriptscriptstyle \perp}$		80	100	S
Peak temperature	T_{P}		245	260	°C
Time within 5 °C of the specified peak	t _P	10	20	30	S
temperature T _P - 5 K					
Ramp-down rate*			3	6	K/s
T _P to 100 °C					
Time				480	S
25 °C to T _P					

All temperatures refer to the center of the package, measured on the top of the component



^{*} slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

Taping 9)



C63062-A1844-B3-04

Tape and Reel 10)



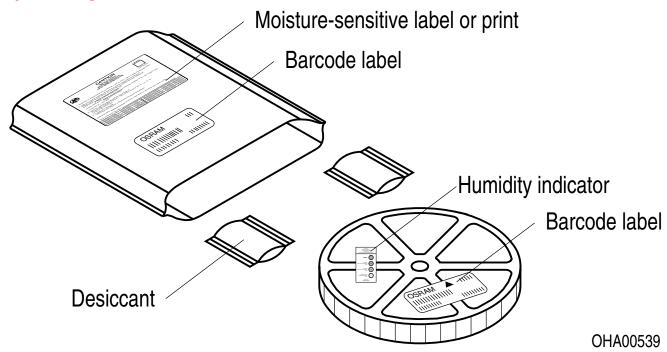
Reel Dimensions

Α	W		N_{\min}	W_1		$W_{2 \text{ max}}$	Pieces per PU
180 mm	·	8 + 0.3 / - 0.1 mm	60 mm		8.4 + 2 mm	14.4 mm	2000
330 mm		8 + 0.3 / - 0.1 mm	60 mm		8.4 + 2 mm	14.4 mm	8000

Barcode-Product-Label (BPL)



Dry Packing Process and Materials 9)



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



Type Designation System

S: 633 T: 528 Y: 587 O: 606 G: 570 P: 560 R: 628 B: 470 H: 648 V: 508	nm amber white nm super red UW: ultra white nm true green yellow nm orange nm green nm pure green nm pure green nm hyper-red nm werde green nm true green nm hyper-red nm true green nm hyper-red hyper-red nm hyper-red hyper-red hyper-red nm hyper-red hyper-re
L	A T 6 7 6
Lead / 6: 7: T: V:	Package Properties folded leads reverse gullwing leads folded leads, improved corrosion stability Au-LF), w/o TiO2 jetting folded leads and UX:3 w/ improved corrosion stability (Au-LF), TiO2 jetting Encapsulant Type / Lens Properties 7: Colorless clear or white volume conversion (resin encapsulation)
	Chip Technology: 1: TSN 3: standard InGaN 4: AIGaAs 5: HOP 2000 6: Standard InGalP 9: TSN low current B: HOP 2000 C: ATON D: Small ThinGaN/ Thinfilm (e.g. 6mil) F: Thinfilm InGaAlP G: ThinGaN(Thinfilm InGaN) K: InGaAlP low current S: standard InGaN low current O: TSN



Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet fall into the class **exempt group (exposure time 10000 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.



Glossary

- Brightness: Brightness values are measured during a current pulse of typically 25 ms, with an internal reproducibility of ± 8 % and an expanded uncertainty of ± 11 % (acc. to GUM with a coverage factor of k = 3).
- Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- Wavelength: The wavelength is measured at a current pulse of typically 25 ms, with an internal reproducibility of ±0.5 nm and an expanded uncertainty of ±1 nm (acc. to GUM with a coverage factor of k = 3).
- Forward Voltage: The forward voltage is measured during a current pulse of typically 8 ms, with an internal reproducibility of ±0.05 V and an expanded uncertainty of ±0.1 V (acc. to GUM with a coverage factor of k = 3).
- Thermal Resistance: Rth max is based on statistic values (6σ) .
- ⁶⁾ **Thermal Resistance:** RthJA results from mounting on PC board FR 4 (pad size 16 mm² per pad)
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- ⁸⁾ Characteristic curve: In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- ¹⁰⁾ **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



Revision History							
Version	Date	Change					
1.3	2021-12-15	Features Maximum Ratings Characteristics Electro - Optical Characteristics (Diagrams) Glossary					



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